# Intel® Storage System SSR212MA Tested Memory List (TML)



Revision 1.0 October 2005

## **Revision History**

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June, 2005	0.9	Review copy.
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**Please Note:** DIMM devices with gold contacts should NOT be placed into DIMM sockets with tin-lead contacts or vice-versa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each Rank on the memory module. Mixing of dissimilar memory manufacturer and similar speeds in each Rank on the memory module is NOT recommended.

# Table of Contents

1. Ove	view of Memory Testing	5
1.1	Paper Qualification	5
1.2	Functional Testing	5
1.3	Computer Memory Test Lab*	5
2. Mem	ory Subsystem	6
2.1	Memory Population	7
2.2	Identifying "Single Rank" or "Double Ranked" DIMMs	9
3. Test	ed Memory	10
	gistered ECC, DDR2-400 DIMM Modules6MB Size (32M x 72)	
Re Re 1G	gistered, ECC, DDR2-400 DIMM Modules 512 MB Sizes (64Mx72) gistered, ECC, DDR2-400 DIMM Modules B Size (128M x 72)	12 14 14
	gistered, ECC, DDR2-400 DIMM Modules B Size (256M x 72)	
4. Sale	s Information	17
5. CMT	L* (Computer Memory Test Labs)	19

### 1. Overview of Memory Testing

The following test processes are used to qualify Dual In-Line Memory Modules (DIMMs) for use with the Intel<sup>®</sup> Storage System SSR212MA. Memory is a vital subsystem in a server. Intel requires that strict guidelines be met before a DIMM vendor is added to the Tested memory List. To be included on the list as a fully supported DIMM, the memory must undergo rigorous tests to ensure that the product will perform the intended server product functions. Memory qualification for Intelerver, workstation and RAID Contoller products is performed both by Intel's Memory Validation Lab (MVL) and by an independent external test lab, Computer Memory Test Lab\* CMTL).

The Tested Memory Lists for Intel's server board, workstation board, and RAID controller products categorize memory modules as advanced tested. The advanced testing process includes a standard paper qualification and then is followed by two levels of functional testing. DIMMs that have completed and passed Advanced Testing are considered to be compatible with the product on which they were tested, and with the test software and operating systems that was used during the test process.

### 1.1 Paper Qualification

A paper qualification is performed to verify that the specifications of a given DIMM meet Intel's memory specifications for a given product. Specification crtieria reviewed include: critical timings, electrical characteristics, timing requirements, environmental requirements, and packaging requirements.

#### 1.2 Functional Testing

After a given DIMM passes the standard paper qualification, functionality of the DIMM is then tested with the intended Intel product. Two levels of functional testing are performed; standard and advanced.

Standard functional testing requires that the given DIMM and Intel product combination operate with no failures for a period of no less than 24 hours for both minimum and maximum DIMM configurations. Testing is performed using a Microsoft\* Windows\* operating system and a custom test package. The test systems operate with standard voltage at room temperature.

Advanced functional testing requires that the given DIMM and Intel product combination operate with no failures for a period of no less than 24 hours for both minimum and maximum DIMM configurations. Testing is performed with multiple operating systems and various custom test packages. Each test configuration is tested with various voltage and temperature margin conditions.

### 1.3 Computer Memory Test Lab\*

Computer Memory Test Lab, also known as CMTL\*, is a leading memory test organization responsible for testing a broad range of memory products. A memory product, which receives a "PASS" after being tested by CMTL, means it functions correctly and consumers can use the product to perform the intended server functions. In order to pass these stringent standards, memory products must maintain the highest manufacturing procedures and pass an exacting battery of tests. Testing is performed with Intel supplied equipment and procedures defined by Intel's various functional testing levels.

#### **CMTL Contact Info:**

> Irvine, CA 92618 http://www.cmtlabs.com/

### 2. Memory Subsystem

The Intel® Storage System SSR212MA is capable of supporting DDR2-400 memory technologies.

NOTE: Industry naming conventions for equivalent memory technologies include the following:

DDR2400 = PC23200.

The following maximum memory capacities are supported based on the number of DIMM slots provided and maximum supported memory loads by the chipset:

16GB maximum capacity for DDR2-400.

NOTE: Because of OS limitations, 4GB is the maximum recommended capacity.

The minimum memory supported with the system running in single channel memory mode is:

256MB for DDR2-400.

Supported DIMM capacities are as follows:

DDR2-400 Memory DIMM sizes include: 256MB, 512MB, 1GB, 2GB, and 4GB.

### 2.1 Memory Population

The Intel® Storage System SSR212MA has six DIMM slots, or three DIMM banks. Both DIMMs in a bank should be identical (same manufacturer, CAS latency, number of rows, columns and devices, timing parameters etc.). Although DIMMs within each bank must be identical, the BIOS supports various DIMM sizes and configurations allowing the banks of memory to be different. Memory sizing and configuration is guaranteed only for qualified DIMMs approved by Intel.

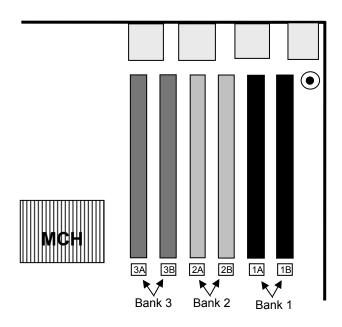


Figure 1. Identifying Banks of Memory

The memory controller is capable of supporting up to 4 loads per channel for DDR2-400. Memory technologies are classified as being either single rank or dual rank depending on the number of DRAM devices that are used on any one DIMM. A single rank DIMM is a single load device, ie) Single Rank = 1 Load. Dual rank DIMMs are dual load devices, ie) Dual Rank = 2 loads.

#### DDR2-400 DIMM population rules are as follows:

- (1) DIMMs banks must be populated in order starting with the slots furthest from MCH
- (2) Dual rank DIMMs are populated before single rank DIMMs
- (3) A maximum of four DIMMs can be populated when all four DIMMs are dual rank DDR2-400 DIMMs

#### The following tables show the supported memory configurations:

- s/r = single rank
- d/r = dual rank
- E = Empty

Table 1: Supported DDR2-400 DIMM Populations

	Bank 3 – DIMMs 3A, 3B	Bank 2 – DIMMs 2A, 2B	Bank 1 – DIMMs 1A, 1B
	S/R	S/R	S/R
	E	S/R	S/R
NACLI	E	Е	S/R
MCH	E	D/R	D/R
	E	Е	D/R
	E	S/R	D/R
	S/R	S/R	D/R

**Note:** On the Intel<sup>®</sup> Storage System SSR212MA, when using all dual rank DDR2-400 DIMMs, a total of four DIMMs can be populated. Configuring more than four dual rank DDR2-400 DIMMs will result in the BIOS generating a memory configuration error.

## 2.2 Identifying "Single Rank" or "Double Ranked" DIMMs

- **x8SR** = x8 Single-Ranked modules have 5 DRAM's on the front and 4 DRAM's on the back with empty spots in between the DRAM's.
- **x8DR** = x8 Double-Ranked modules have 9 DRAM's on each side for a total of 18 (no empty slots)
- x4SR = x4 Single-Ranked modules have 9 DRAM's on each side for a total of 18 and look similar to x8 Double-Ranked
- **x4DR** = x4 Double-Ranked modules have 18 (stacked) DRAM's on each side for a total of 36

	DDR2-400 Registered SDRAM Module Matrix										
DIMM Capacity	DIMM Organization	SDRAM Density	SDRAM Organization	# SDRAM Devices/rows/Ranks	# Address bits rows/Ranks/column	Ranked					
256MB	32M x 72	256Mbit	32M x 8	9/1/4	13/2/10	Single Ranked					
512MB	64M x 72	256Mbit	64M x 4	18/1/4	13/2/11	Single Ranked					
512MB	64M x 72	256Mbit	32M x 8	18/2/4	13/2/10	Double Ranked					
512MB	64M x 72	512Mbit	64M x 8	9/1/4	14/2/10	Single Ranked					
1GB	128M x 72	512Mbit	128M x 4	18/1/4	14/2/11	Single Ranked					
1GB	128M x 72	512Mbit	64M x 8	18/2/4	14/2/10	Double Ranked					
1GB	128M x 72	1Gbit	128M x 8	9/1/8	14/3/10	Single Ranked					
2GB	256M x 72	1Gbit	256M x 4	18/1/8	14/3/11	Single Ranked					
2GB	256M x 72	1Gbit	128M x 8	18/2/8	14/3/10	Double Ranked					
2GB	256M x 72	2Gbit	256M x 8	9/1/8	15/3/10	Single Ranked					
4GB	512M x 72	2Gbit	256M x 8	18/2/8	15/3/10	Double Ranked					
4GB	512M x 72	2Gbit	512M x 4	18/1/8	15/3/11	Single Ranked					

#### 3. Tested Memory

The following tables list DIMM devices tested to be compatible with the Intel<sup>®</sup> Storage System SSR212MA. The list of tested memory is periodically updated as qualified memory is added during the production life of the Intel product.

Intel strongly recommends the use of ECC memory in all storage server products.

Memory modules not listed in the following tables have not been tested for compatibility and their use with the Storage System SSR212MA may result in unpredictable operation and data loss.

**Caution**: Third party memory vendors may use the same module part number with different DRAM vendors and die revisions. To insure proper system operation, verify that each DRAM vendor and die revision has been separately tested and qualified. Please notify CMTL if there is a discrepancy. This list is subject to change without notice.

**Note**: This list is not intended to be all-inclusive. It is provided as a convenience to Intel's general customer base, but Intel does not make any representations or warranties whatsoever regarding the quality, reliability, functionality, or compatibility of these memory modules.

Registered ECC, DDR2-400 DIMM Modules 256MB Size (32M x 72)									
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	Lead Free	DRAM Organiz ation	Rank	EOL
Samsung	M393T3253FG0- CCC Date Code: 0521	K4T56083QF-GCCC	Samsung		9/22/04		(32Mx8)* 9	x8SR	
Micron	MT9HTF3272Y- 40EB2	MT47H32M8BP-37E	Micron		9/22/04		(32Mx8)* 9	x8SR	
Infineon	HYS72T32000HR -5-A	HYB18T256800AF5-A	Infineon		9/22/04		(32Mx8)* 9	x8SR	
+ATP Electronics	AH32K72N8BQC 4M	MT47H32M8BP(FP)- 37E rev	Micron	SH240N08K 1	11/16/04		(32Mx8)* 9	x8SR	
+Buffalo	D2R400A- ES256MBJ	MT47H32M8BP(FP)-5E rev B	Micron	2DRA18F- BA	12/7/04		(32Mx8)* 9	x8SR	
Samsung	M393T3253FZ0- CCC Date Code: 0521	K4T56083QF-ZCCC	Samsung		2/24/05	Yes	(32Mx8)* 9	x8SR	
+ATP Electronics	AH32K72N8BQC 4S	K4T56083QF-GCD5 rev F	Samsung	SH240N08K 1	5/4/05		(32Mx8)* 9	x8SR	

CCC

SM647RDR26483

5IA

S506472J20A-50A

AH64K72M4BQC4

S

KVR400D2R3/512

M393T6453FG0-

CCC

Date Code: 0521

39C921284B-L

D2R400A-

E512MBJ

MT18HTF6472Y-

40EB2 HYMP564R728-E3

AA

75.963A1.565

HYS72T64001HR-

5-A

DTM63311C

M393T6553BZ0-

CCC

M393T6453FZ0-

CCC

Date Code: 0521 M393T6450FZ0-

CCC

Date Code: 0521

Samsung

+Smart

Modular

Technologies

+Legacy

Electronics

Inc. +ATP

Electronics

Kingston

Samsung

+Wintec

Industries

+Buffalo

Micron

Hynix

+Apacer

Infineon

+Dataram

Samsung

Samsung

Samsung

Registered, ECC, DDR2-400 DIMM Modules 512 MB Sizes (64Mx72)									
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	Lead Free	DRAM Organiz ation	Rank	EOL
Samsung	M393T6450FG0- CCC Date Code: 0521	K4T56043QF-GCCC	Samsung		9/22/04		(64Mx4)* 18	SR	
Infineon	HYS72T64000HR- 5-A	HYB18T512800AF	Infineon		9/22/04		(64Mx8)* 9	SR	
Infineon	HYS72T64020HR- 5-A	HYB18T256800AF5-A	Infineon		9/22/04				
+Smart Modular Technologies	SM647RDR26483- 5-I	HYB18T512800AF(AC) 5 rev A	Infineon	240-11-4 rev C	10/21/04		(64Mx8)* 9	SR	
Samsung	M393T6553BG0-	K4T51083OB-GCCC	Samsung		10/28/04		(64Mx8)*	SR	

Samsung

Infineon

Infineon

Samsung

Infineon

Samsung

Samsung

Micron

Micron

Hynix

Samsung

Infineon

Samsung

Samsung

Samsung

Samsung

K4T51083QB-GCCC

HYB18T512800AC5

rev A

HYB18T256400AF5 rev

K4T56043QF-GCCC

rev F

HYB18T512800AF5 rev

K4T56083QF-GCCC

K4T51083QB-GCD5

rev B MT47H32M8BP(FP)-5E

rev B

HY5PS12821-F-E3

K4T51083QB-GCCC

rev B

HYB18T256400AF5-A

K4T56043QF-GCCC

rev F

K4T51083QB-ZCCC

K4T56083QF-ZCCC

K4T56043QF-ZCCC

10/28/04

10/28/04

10/28/04

11/29/04

12/9/04

12/6/04

12/13/04

12/13/04

12/20/04

1/31/05

1/31/05

2/24/05

2/24/05

2/24/05

Yes

Yes

Yes

P54G240NE

LE18DD2F2

SH240M04K

2025263-

001.A00

D2R872

2DRB28F-

BA

48.16188.01

1 rev 1

40011A rev

Α

BUB1RA rev 11/4/04

404RRH rev 11/11/04

SR

SR

SR

SR

SR

DR

SR

DR

SR

SR

SR

SR

SR

DR

SR

9

(64Mx8)\*

9

(64Mx4)\*

18

(64Mx4)\*

18

(64Mx8)\*

9

(32Mx8)\*

18

(64Mx8)3

(32Mx8)<sup>2</sup>

18

(64Mx8)3

(64Mx8)3

(64Mx4)3

18

(64Mx4)3

18

(64Mx8)\*

9

(32Mx8)\*

18

(64Mx4)\*

18

+Apacer	75.963A1.573	K4T51083QB-ZCCC rev B	Samsung	48.16188.01 1 rev 1	3/1/05		(64Mx4)* 18	SR	
+Kingston	KVR400D2S8R3/5 12I	HYB18T512800AF37 rev A	Infineon	2025263- 001.A00 rev A	4/27/05		(64Mx8)* 9	SR	
Samsung	M393T6553CZ0- CCC	K4T51083QC-ZCCC	Samsung		5/2/05		(64Mx8)* 9	SR	
+ATP Electronics	AH64K72N8BHC4 S	K4T51083QB-GCCC rev B	Samsung	SH240N08K 1	5/12/05		(64Mx8)* 9	SR	
+Legacy Electronics Inc.	L506472K20A-50A	G64Mx8DDR2	Legacy	LE9DD2F24 08RRA rev A	6/7/05		(64Mx8)* 9	SR	
+Apacer	76.92220.B07	K4T51083QB-ZCD5 rev B	Samsung	48.16188.01 1 rev 1	6/22/05		(64Mx8)* 9	SR	
+Apacer	76.92220.B12	HYB18T512800AF5 rev A	Infineon	48.16188.01 1 rev 1	6/23/05		(64Mx8)* 9	SR	
+Viking	VR5ER647218EB PL1	MT47H64M8CB-37E rev B	Micron	0000992A rev A	6/20/05		(64Mx8)* 9	SR	
+Apacer	76.92220.B03	K4T51083QB-ZCCC rev B	Samsung	48.16188.01 1 rev 1	6/30/05		(64Mx8)* 9	SR	
+Apacer	76.92220.B13	EDE5108AESK-5C-E rev E	Elpida	48.16188.01 1 rev 1	7/11/05		(64Mx8)* 9	SR	
+Kingston	KVR400D2S8R3/5 12I	HYB18T512800AF37 rev A	Infineon	2025263- 001.C00 na	7/5/05		(64Mx8)* 9	SR	
Infineon	HYS72T64000HR- 5-A	HYB18T512800AC5	Infineon		7/8/05	Yes	(64Mx8)* 9	SR	

	Registered, ECC, DDR2-400 DIMM Modules 1GB Size (128M x 72)								
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	Lead Free	DRAM Organiza tion	Rank	EOL
Micron	MT18HTF12872Y -40EA2	MT47H128M8 FP	Micron		9/22/04		(128Mx4) *18	SR	
+Dataram	DTM63310A	HYB18T5124 00AF5 rev A	Infineon	40011A rev A	10/15/04		(128Mx4) *18	SR	
+Smart Modular Technologies	SM1287RDR2124 35IA	HYB18T5124 00AC5 rev A	Infineon	P54G240NESU BRCC rev A	10/22/04		(128Mx4) *18	SR	
Hynix	HYMP512R724- E3 AA-A	HY5PS12421- F-E3	Hynix		10/28/04		(128Mx4) *18	SR	
+Wintec Industries	39C931284B-L	K4T51083QB- GCD5 rev B	Samsung	D2R872	11/9/04		(64Mx8)* 18	DR	
+Smart Modular Technologies	SM1287RDR2124 35IA	HYB18T5124 00AC5 rev A	Infineon	P54G240NESU BRCC rev A	10/22/04		(128Mx4) *18	SR	
+Smart Modular Technologies	SM1287RDR2124 35SB	K4T51043QB- GCCC rev B	Samsung	P54G240NESU BRCC rev A	11/17/04		(128Mx4) *18	SR	
+Wintec Industries	39S931281A-L	HYB18T5128 00AF5 rev A	Infineon	D2R872	11/18/04		(64Mx8)* 18	DR	
+ATP Electronics	AH28K72M4BHC 4S	K4T51043QB- GCCC rev B	Samsung	SH240M04K1	11/23/04		(128Mx4) *18	SR	
+Legacy Electronics Inc.	S512872M20A- 50A	HYB18T5124 00AF(C)5 rev A	Infineon	LE18DD2F2404 RRH rev 1	11/24/04		(128Mx4) *18	SR	
+Smart Modular Technologies	SM1287RDR2124 3-5-I	HYB18T5124 00AC5 rev A	Infineon	240-13-4	11/30/04		(128Mx4) *18	SR	
+Dataram	DTM63310F	K4T51043QB- GCCC rev B	Samsung	40011A rev A	12/9/04		(128Mx4) *18	SR	
Samsung	M393T2953BG0- CCC	K4T51083QB- GCCC	Samsung		12/14/04		(64Mx8)* 18	DR	
+Smart Modular Technologies	SM1287RDR2124 3-5-S	K4T51043QB- GCCC rev B	Samsung	M393T2950BG 0	12/23/04		(128Mx4) *18	SR	
+Apacer	75.072A1.564	K4T51043QB- GCCC rev B	Samsung	48.16189.011 rev 1	12/21/04		(128Mx4) *18	SR	
+Smart Modular Technologies	SB1287RDR2124 35IA	HYB18T5124 00AF5 rev A	Infineon	PB54G240NES UBRCC1 rev A	1/7/05		(128Mx4) *18	SR	
Kingston	KVR400D2R3/1G	E5104AB-4A- E rev B	Elpida	2025248-001 rev 0.5	1/14/05		(128Mx4) *18	SR	
Netlist Inc	NLD127R212038- D32KSB	K4T51043QB- GCCC rev B	Samsung	0208-10 rev A	2/2/05		(128Mx4) *18	SR	
Samsung	M393T2953BZ0- CCC	K4T51083QB -ZCCC	Samsung		2/24/05	Yes	(64Mx8)* 18	DR	
+Smart Modular Technologies	SM1287RDR2124 3-5-H	HY5PS12421 F-E3 rev A	Hynix	E72369	2/16/05		(128Mx4) *18	SR	
Samsung	M393T2950BG0- CCC Date Code: 0521	K4T51043QB- GCCC	Samsung		2/28/05		(128Mx4) *18	SR	
+Viking	VR5ER287214EB PL1	MT47H128M4 BT-37E rev A	Micron	0001009A rev A	3/14/05		(128Mx4) *18	SR	
Samsung	M393T2953CZ0- CCC	K4T510830C- ZCCC	Samsung		3/22/05		(64Mx8)* 18	DR	
Netlist Inc	NLD127R21203F- D32KSB	K4T51043QB -ZCCC rev B	Samsung	0208-10 rev A	3/16/05	Yes	(128Mx4) *18	x4SR	

+Legend	L12723C7- RCAH2HBF	HY5PS12821 F-E3 rev A	Hynix	B62RRCA rev	3/16/05		(64Mx8)* 18	DR	
+Viking		MT47H128M4 BT-37E rev A	Micron	0001009A rev A	3/14/05		(128Mx4) *18	SR	
+Viking	VR5ER287218EB PL1	K4T51083QB- ZCD5 rev B	Samsung	0000992A rev A	3/16/05		(64Mx8)* 18	DR	
Samsung	M393T2950BZ0- CCC Date Code: 0521	K4T51043QB -ZCCC	Samsung		4/14/05	Yes	(128Mx4) *18	SR	
Infineon	HYS72T128000H R-5-A	HYB18T5124 00AF5	Infineon		4/27/05		(128Mx4) *18	SR	
+Ventura Technology Group	D2-54KF53SV- 333	K4T51043QB- ZCCC rev B	Samsung	D2R472	4/21/05		(128Mx4) *18	SR	
+Apacer	75.072A1.574	K4T51043QB- ZCCC rev B	Samsung	48.16189.011 rev 1	4/18/05		(128Mx4) *18	SR	
+Netlist, Incorporated	NLD127R212038- D32KIA	HYB18T5124 00AF5 rev A	Infineon	0208-10 rev A	4/21/05		(128Mx4) *18	SR	
+Kingston	KVR400D2S4R3/ 1GI	E5104AE-5C- E rev E	Elpida	2025248- 001.B00	5/9/05		(128Mx4) *18	SR	
Transcend Information	TS128MQR72V4 K	K4T51043QB- GCCC rev B	Samsung	09-2090	5/5/05		(128Mx4) *18	SR	
Corsair	CM73DD1024R- 400/S	K4T51043QB- ZCD5 rev B	Samsung	50-00129 rev A	5/25/05		(128Mx4) *18	SR	
+Wintec Industries	39S931341A-L	HYB18T5124 00AF5 rev A	Infineon	D2R472	6/1/05		(128Mx4) *18	SR	
+Apacer	78.01068.331	HYB18T5124 00AF5 rev A	Infineon	48.16189.011 rev 1	5/31/05		(128Mx4) *18	SR	
SimpleTech	ST72P4T128M- A05AU	K4T51043QB- ZCCC rev B	Samsung	E186014	5/27/05		(128Mx4) *18	SR	
+Legacy Electronics Inc.	B512872M20A- 50A	K4T51043QB- GCCC rev B	Samsung	LE18DD2F2404 RRH rev A	6/14/05		(128Mx4) *18	SR	
+Apacer	76.02220.B11	K4T51043QB- ZCCC rev B	Samsung	48.16189.011 rev 1	6/27/05		(128Mx4) *18	SR	
+Viking	VR5ER287218EB PL3	MT47H64M8 CB-37E rev B	Micron	0000992A rev A	6/24/05		(64Mx8)* 18	DR	
+Smart Modular Technologies	SB1287RDR2124 3-5-H	HY5PS12421 FP-E3 A 1st Generation	Hynix	E72369 na	7/14/05		(128Mx4) *18	SR	
+Apacer	76.02220.B06	HYB18T5124 00AF5 rev A	Infineon	48.16189.011 rev 1	7/12/05		(128Mx4) *18	SR	
+Wintec Industries	39C931344B-GL	K4T51043QB- ZCCC rev B	Samsung	D2R472 na	7/7/05		(128Mx4) *18	SR	
+Avant Technology	AVF7228R52E34 00F0-MTB	MT47H64M8 CB-37E rev B	Micron	50-1431-01B rev B	6/29/05		(64Mx8)* 18	DR	
Samsung	M393T2950CZ0- CCC	K45T1043QC- ZCCC	Samsung		7/8/05		(128Mx4) *18	SR	
Infineon	HYS72T128020H R-5-A	HYB18T5128 00AF5-A	Infineon		7/25/05		(64Mx8)* 18	DR	
+Smart Modular Technologies	SB1287RDR2124 3-5-E	E5104AB-4A- E rev B	Elpida	Z10 026A na	08/02/05		(128Mx4) *18	SR	
+Legacy Electronics Inc.	L512872M20A- 50A	BGA128X4DD R2NC (DDR DAT)	Legacy	LE18DD2F2404 RRH rev A	08/17/05		(128Mx4) *18	SR	

Registered, ECC, DDR2-400 DIMM Modules 2GB Size (256M x 72)									
Manufacturer	Part Number	DRAM Part Number	DRAM Vendor	PCB Part Number	Date	Lead Free	DRAM Organiza tion	Rank	EOL
+Smart Modular Technologies	3-5-I	HYB18T512400AC5 rev A	Infineon	240-20-1	11/12/04		(128Mx4) *36	DR	
+Legacy Electronics Inc.	S525672M20A- 50A	HYB18T512400AF5 rev A	Infineon	TTM-SA2 rev 1	11/2/04		(128Mx4) *36	DR	
Samsung	M393T5660MZ0- CCC	K4T1G044QM- ZCCC	Samsung		11/29/04		(256Mx4) *18	SR	
+Dataram	DTM63309A	HYB18T512400AF5 rev A	Infineon	40040A rev A	12/1/04		(128Mx4) *36	DR	
+Legacy Electronics Inc.	8AL6MDGM- 1PDG	BGA128MX4DDRN C	Legacy	LE36DDF1844 RRF rev B	12/6/04		(128Mx4) *36	DR	
Micron	MT18HTF25672Y -40EA2		Micron		12/13/04		(256Mx4) *18	SR	
+Smart Modular Technologies	SM2567RDR2128 3-5-S	K4T51043QB- SCCC rev B	Samsung	M393T5750BS 1	12/27/04		(128Mx4) *36	DR	
Samsung	M393T5750BS0- CCC Date Code: 0521	K45T1043QB- SCCC	Samsung		1/10/05		(128Mx4) *36	DR	
Samsung	M393T5750BY0- CCC Date Code: 0521	K45T1043QB- ZCCC	Samsung		2/24/05	Yes	(128Mx4) *36	DR	
+Dataram	DTM63320A	HYB18T1G400AF-5 rev A	Infineon	40011A rev A	3/10/05		(256Mx4) *18	SR	
+Smart Modular Technologies	SB2567RDR2128 35IA	HYB18T512400AF5 rev A	Infineon	PB52G240NES UB1RJ	2/28/05		(128Mx4) *36	DR	
+ATP Electronics	M	MT47H256M4BT-5E rev A	Micron	SH240M04K1	3/7/05		(256Mx4) *18	SR	
+ATP Electronics	AH56K72J4BHC4 C	HYB18T512400AF5 rev A	Infineon	SH240J04K1	3/24/05		(128Mx4) *36	DR	
+Smart Modular Technologies	SM2567RDR2254 3-5-I	HYB18T1G400AF-5 rev A	Infineon	240-13-5	3/30/05		(256Mx4) *18	SR	
+Smart Modular Technologies	SM2567RDR2254 3-5-S	K4T1G044QM- ZCCC rev M	Samsung	M393T2950BG 0	4/15/05		(256Mx4) *18	SR	
Netlist, Incorporated	D32KIA	HYB18T512400AF5 rev A	Infineon	0203-10 rev A	4/18/05		(128Mx4) *36	DR	
Infineon	HYS72T256000H R-5-A	HYB18T1G400AF-5	Infineon		5/4/05		(256Mx4) *18	SR	
+Kingston	KVR400D2D4R3/ 2GI	E5104AE-5C-E rev E	Elpida	2025292- 001.A00	5/3/05		(128Mx4) *36	DR	
+Smart Modular Technologies	SG2567RDR2128 35IA	HYB18T512400AF5 rev A	Infineon	PG52G240NES UB1RJ rev A	6/10/05		(128Mx4) *36	DR	
+Apacer	76.A2220.B10	HYB18T512400AF5 rev A	Infineon	48.1A189.012 rev 2	6/16/05		(128Mx4) *36	DR	
+Dataram	DTM63309B	K4T51043QC- ZCCC rev C	Samsung	40040A rev A	7/25/05		(128Mx4) *36	DR	
+Wintec Industries	39C941441A-L	HYB18T1G400AF-5 rev A	Infineon	D2R472 na	7/1/05		(256Mx4) *18	SR	

## 4. Sales Information

Vendor Name	Web URL	Vendor Direct Sales Info
ATP Electronics	http://www.atpusa.com/	Florence Hsieh
		Tel 408-732-5831
		Fax 408-732-5055
		sales@atpusa.com
ATP Electronics	http://www.atpusa.com/	Patty Kuo
Taiwan Inc.		Tel 011-886-2-2659-6368
		Fax 886-2-2659-4982
Avant Technology	http://www.avanttechnology.com	Brad Scoggins
0,		Phone: (512)491-7411
		Fax: (512)491-7412
		brads@avanttechnology.com
Aved Memory Products	http://www.avedmemory.com/	
Buffalo Technology	http://www.buffalotech.com/	(800) 967-0959 memory@buffalotech.com
Centon Electronics	http://www.conton.com	Tel: 949-855-9111
Centon Electronics	http://www.centon.com	Fax: 949-855-6035
Corsair	http://www.corsairmicro.com/	Tel: 510-657-8747
Ouisali	<u>πτιμ.//www.corsairmicro.com/</u>	Fax: 510-657-8747
Dane-Elec	http://www.dane-memory.com/	Michal Hassan @ (949)450-2941 or email
Daile-Elec	http://www.dane-memory.com/	@ Michal@Dane-memory.com
Dataram	http://www.dataram.com/	Paul Henke, 800-328-2726 x2239 in USA
Dataram	http://www.dataram.com/	phenke@dataram.com
		Peter Jauss, +49-69-680-9070 in EMEA
		pjauss@dataram.com
GoldenRAM	http://www.goldenram.com	Jason M. Barrette @ 800-222-861 x7546
301aoin t-ain	mapwww.gordornam.com	jasonb@goldenram.com
		or Michael E. Meyer @800-222-8861
		x7512 michaelm@goldenram.com
Hitachi	http://semiconductor.hitachi.com/pointer/	
Hyundai/Hynix	http://www.hea.com/	
Semiconductor		
Infineon	http://www.infineon.com/business/distribut/ind	
	<u>ex.htm</u>	
ITAUCOM	http://www.itaucom.com.br	
JITCO CO LTD	http://www.jitco.net/	Seong Jeon
		Tel: 82-32-817-9740
		s.jeon@jitco.net
Kingston	http://www.kingston.com	US Call (877) 435-8726
		Asia – Call 886-3-564-1539
	I the theory and the terms of t	Europe – Call +44-1932-755205
Legacy Electronics Inc.	http://www.legacyelectronics.com	U.S. Contact: Keri Albers 888 466 3853
		ext. 307
Legend	http://www.legend.com.au	European Contact: 49 89 370 664 11
Micron	http://silicon.micron.com/mktg/'http://silicon.mi	
WILCIOII	cron.com/mktg/mbqual/qual_data.cfm	
MSC Vertriebs GmbH	http://www.msc-ge.com	William Perrigo
		49-7249-910-417
		Fax: 49-7249-910-229
		wpe@msc-ge.com
Netlist, Inc	http://www.netlistinc.com	Christopher Lopes
Methot, inc	Http://www.netiistinc.com	Official Lopes
Netiist, iiic	nup.//www.netiistinc.com	949.435.0025 tel
Netilst, inc	nttp://www.netiistinc.com	

Vendor Name	Web URL	Vendor Direct Sales Info

Peripheral Enhancements	http://www.peripheral.com/	
Samsung	http://www.korea.samsungsemi.com/lo	For US customers go to:
	cate/buy/list_na.html	http://www.mymemorystore.com/
Silicon Tech	http://www.silicontech.com/contact/sale	
	scontacts.shtml	
Simple Tech	http://www.simpletech.com	Ron Darwish @ (949) 260-8230 or email @
		Rdarwish@Simpletech.com
SMART Modular	http://www.smartm.com/channel	Gene Patino
Technologies		(949) 439-6167
		Gene.Patino@Smartm.com
Swissbit	http://www.swissbit.com	Tony Cerreta
		Tel: 914-935-1400 x240
		Fax: 914-935-9865
		tony.cerreta@swissbitna.com
TechnoLinc Corporation	http://www.technolinc.com	David Curtis
		510-445-7400
		davidc@technolinc.com
TRS* Tele-Radio-Space	http:/www.certified-memory.com	Vendor Direct Sales Info: Andreas Gründl, Pho.:
GmbH	http://www.certified-memory.de	+49(0)89/94553234, Fax.:
		+49(0)89/94553293,
		agruendl@trs-space.de
Unigen	http://www.unigen.com	
Ventura Technology Inc	http://www.venturatech.com	Don Hummel @ 805-581-0800 x 108 or email @
		don@venturatech.com
Viking InterWorks	http://www.vikinginterworks.com	
Virtium Technology Inc	http://www.virtium.com	Tod Skelton @ (949) 460-0020 ext. 146 or email
-		@ tod.skelton@virtium.com
Legend	http://www.legend.com.au	Tel: 800-338-2361
-		Fax: 949-459-8577
		orderdesk@vikingcomponents.com
Wintec Industries	http://www.wintecindustries.com	Tel 510-360-6300
		Fax 510-770-9338

#### 5. CMTL\* (Computer Memory Test Labs)

CMTL is a privately owned and operated memory testing organization responsible for testing a broad range of memory products. Memory devices tested by CMTL must undergo a rigorous battery of tests to ensure that the product will perform the intended server functions. Memory capability is a major factor your customers consider. CMTL has the ability to test and certify memory on Intel-based server platforms. The list of memory modules, which have undergone testing through the CMTL facility, should be referenced when considering modules for integration into this Intel server product. Stringent standards with regard to manufacturing procedures and quality must be met to pass the exacting tests required for qualification through the independent testing facility. Testing is performed by CMTL with Intel server products and test procedures defined by Intel's Memory Qualification Lab. Intel routinely audits the CMTL facility to ensure all procedures, process handling, and testing methodologies are met.

#### **IMPORTANT NOTE**

DIMM devices with gold contacts should NOT be placed into DIMM sockets with tin-lead contacts or viceversa. Mixing dissimilar metal contact types has been shown to result in unreliable memory operation. Intel recommends similar manufacturer and similar speeds in each Rank on the memory module. Mixing of dissimilar memory manufacturer devices or dissimilar memory device speeds is not recommended. This document contains information which is the proprietary property of Intel Corporation. Nothing in this document constitutes a guaranty, warranty, or license, express or implied. Intel has tested the following DIMMs for minimum electrical and functional compatibility with the Intel® Storage System SSR212MA. This listing is not intended to be all inclusive; it only represents the DIMMs Intel or CMTL has tested. Users of this list are reminded to check with the DIMM manufacturer or Distributor to ensure that a particular DIMM model is adequate for the intended purpose on the Intel® Storage System SSR212MA. Intel provides no indemnities for and expressly disclaims all liabilities for any and all such guaranties, representations, and warranties (oral or written) whether express or implied, related to DIMMs in a Intel<sup>®</sup> Storage System SSR212MA, including without limitation to: fitness for a particular purpose; merchantability; noninfringement of intellectual property or other rights of any third party or of Intel. The reader is advised that third parties may have intellectual property rights which may be relevant to this document and the technologies discussed herein, and is advised to seek the advice of competent legal counsel, without obligation of Intel. Intel retains the right to make changes to this document at any time, without notice. Intel makes no warranty or representation with respect to the use of this document or reliance by the reader upon its contents, and assumes no responsibility for any errors which may appear in the document nor does it make a commitment to update the information contained herein.

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